

### SVT Background Study with FullSim

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SuperB Bkg Weekly Meeting

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## Open issues

- •Bkg rate (mainly from pairs) below 20 MHz/cm<sup>2</sup>, which radius for L0?
  - Striplets, 200um Si
  - Pixel, 50um Si
- Hot spots, Z-Phi distribution
- Radiation on L0 electronics
  - New volume and additional G4 steps list
- Radiative Bhabha background with B field turned on (waiting for details on compensation from IR people)

•Note: results here with r356, no diff compared to Feb production

### Rate for pixel and striplet devices

# L0 thickness changed to 50 and 200um L0 radius 13 -> 23mm



### Phi-Z cluster distribution (L 0,1,2)

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• Check for hot spots, not visible •Average on z scale by arrow



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Clusters2 distribution vs Z and Phi on Svt Layer 1

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### Phi-Z cluster distribution (L 3,4,5)

- •Check for hot spots, not visible
- •Average on z scale by arrow
- More statistics for outer layers



Clusters2 distribution vs Z and Phi on Svt Layer 4



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#### Radiation on L0 electronics

- •Additional 2 volumes around IR tungsten cones close to L0, 1mm of silicon at 2mm of distance, just as a radiation probe
- •Sensitive volumes, additional BrnRootHits list dumped
- •Average dose: **460 krad** (only pairs bkg)
- •Much higher close to L0 edges, ~2 Mrad
- •Other areas can be easily tested using also more realistic materials



## RadBhabha with B field on (1)

•Waiting for final configuration of magnetic field around IP

- Compensation: field on inside L0 but not upstream and down stream to avoid off energy particles to be driven into the shielding
- For best results with pairs bkg B field in IR has been turned on by hand (hardcoded in Bruno, off by default in svn rep)
  Problems also with RadBhabha, comparison with B field Off (Feb Prod, 300umSi, r13mm) / On (500k evts, 200umSi, r13mm)



### RadBhabha with B field on (2)

- R-Z distrib for origin of tracks that generate clusters in L0
- Again low statistics
- •B field on, 2 bins at 0,  $2 \ge 20 \ge 400 = 16k$
- •B field off, 32k



### RadBhabha with B field on (3)

Cluster rate z distribution: Feb Prod (B off) vs Test (B On)
Factor 400 in statistics, not easy to compare the results but decrease in cluster rate is clear



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# RadBhabha with B field on (4)

Total cluster and pixel rates for all the layers
B field on lowers by a factor 2 the cluster rate everywhere
Pixel rates for L0 affected also by Si thickness (300 vs 200um)

Svt Layer	Cluster Rate (kHz/cm <sup>2</sup> )		Pixel Rate (kHz/cm <sup>2</sup> )	
B field	B off	B on	B off	B on
Layer 0	858	417	8016	2840
Layer 1	62	33	116	65
Layer 2	38	14	71	83
Layer 3	15	11	28	22
Layer 4	3.4	4.4	5.4	6.9
Layer 5	2.1	3.1	3.4	5.3

### RadBhabha with B field on (5)

Pixel rate z distribution: Feb Prod (B off) vs Test (B On)
With B field On the pixel rate is 5% of value for bkg pairs using the same configuration



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#### Conclusion

- Minimum radius for L0 considering bkg pairs only
  - Pixels: 13mm
  - Striplets: 19mm
- •No visible hot spots, more statistics need for outer layers
- •High level of radiation close to L0 just outside the tungsten shielding, share info with people that design FEE
- B field on in the IR moves down rates by a factor 2, not big as expected
  - Waiting for final configuration for B field at IR